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NTE621

Silicon Rectifier, General Purpose, High Voltage, Standard Recovery DO-213AB Surface Mount Type Case

Features:

- High Temperature Metallurgically Bonded
- Glass Passivated Junction
- High Temperature Soldering Guaranteed:
 +450°C/5 Seconds at Terminals. Complete Device Submersible Temperature of
 +260°C/10 Seconds in Solder Bath.

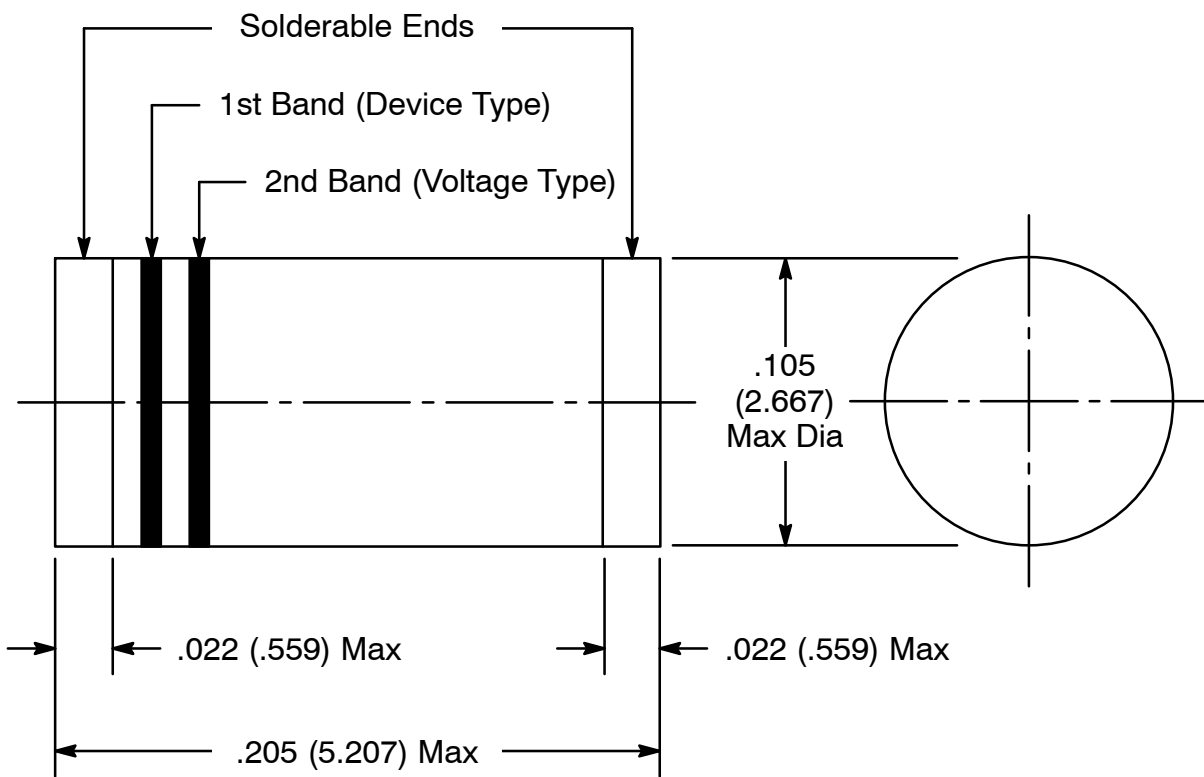
Maximum Ratings and Electrical Characteristics: ($T_A = +25^\circ\text{C}$ unless otherwise specified.
 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.)

Maximum Recurrent Peak Reverse Voltage, V_{RRM}	400V
Maximum RMS Voltage, V_{RMS}	280V
Maximum DC Blocking Voltage, V_{DC}	400V
Maximum Average Forward Rectified Current, $I_{T(AV)}$	1A
Peak Forward Surge Current, I_{FSM} (8.3ms Single Half Sine-Wave Superimposed on Rated Load)	30A
Maximum Instantaneous Forward Voltage ($I_T = 1A$), V_F	1.1V
Maximum DC Reverse Current ($V_{DC} = 400V$), I_R	
$T_A = +25^\circ\text{C}$	10 A
$T_A = +125^\circ\text{C}$	50 A
Maximum Full Load Reverse Current (Full Cycle Average at $T_A = +75^\circ\text{C}$), $I_{R(AV)}$	30 A
Typical Junction Capacitance (Note 1), C_J	15pF
Operating Junction Temperature Range, T_J	-65° to +175°C
Storage Temperature Range, T_{stg}	-65° to +175°C
Maximum Thermal Resistance, Junction-to-Terminal (Note 2), R_{thJL}	30°C/W
Maximum Thermal Resistance, Junction-to-Ambient (Note 3), R_{thJA}	75°C/W

Note 1. Measured at 1MHz and applied reverse voltage of $4V_{DC}$.

Note 2. Thermal resistance, junction-to-terminal, 6.0mm² copper pads to each terminal.

Note 3. Thermal resistance, junction-to-ambient, 6.0mm² copper pads to each terminal.



Two Bands Indicates Cathode